

## N-Channel 30-V (D-S) MOSFET

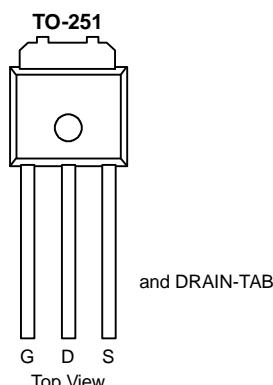
PRODUCT SUMMARY		
V <sub>DS</sub> (V)	r <sub>D(on)</sub> (Ω)	I <sub>D</sub> (A) <sup>a</sup>
30	0.012 @ V <sub>GS</sub> = 10 V	17.5
	0.0175 @ V <sub>GS</sub> = 4.5 V	14.5

### FEATURES

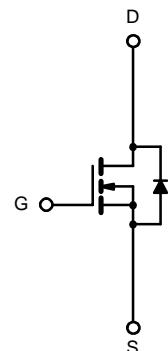
- TrenchFET® Power MOSFET

### APPLICATIONS

- DC/DC Converters
- Synchronous Rectifiers



Order Number:  
SUU50N03-12P



N-Channel MOSFET

### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	30	V
Gate-Source Voltage	V <sub>GS</sub>	±20	
Continuous Drain Current <sup>a</sup>	I <sub>D</sub>	17.5	A
		12.4	
Pulsed Drain Current	I <sub>DM</sub>	40	A
Continuous Source Current (Diode Conduction) <sup>a</sup>	I <sub>S</sub>	5	
Avalanche Current	I <sub>AS</sub>	30	mJ
Single Pulse Avalanche Energy	E <sub>AS</sub>	45	
Maximum Power Dissipation	P <sub>D</sub>	46.8	W
		6.5 <sup>a</sup>	
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to 175	°C

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>a</sup>	R <sub>thJA</sub>	18	23	°C/W
		40	50	
Maximum Junction-to-Case	R <sub>thJC</sub>	2.6	3.2	

Notes

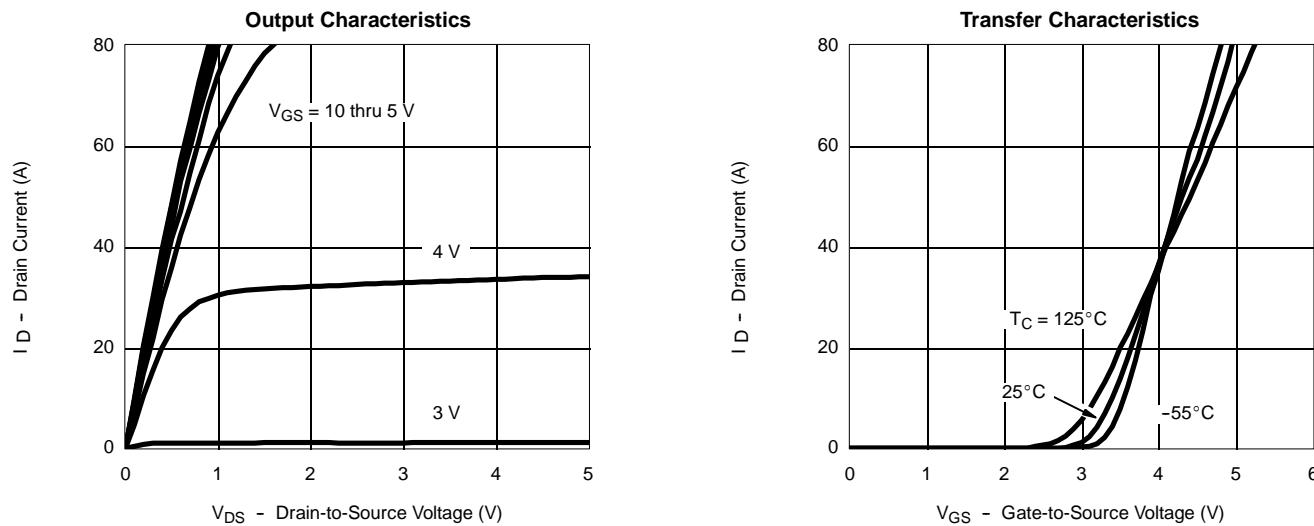
a. Surface Mounted on FR4 Board, t ≤ 10 sec.

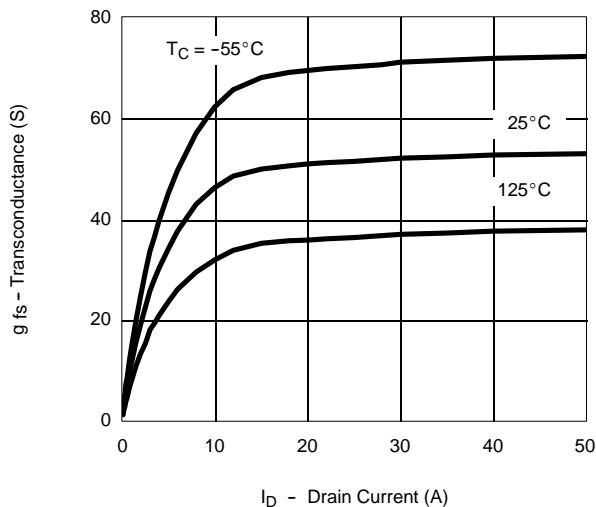
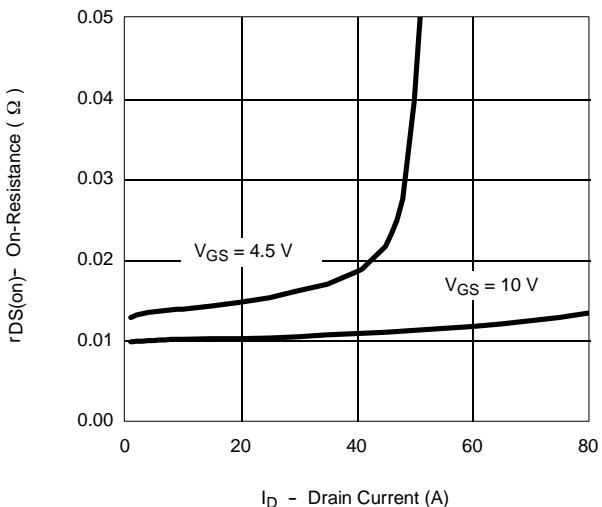
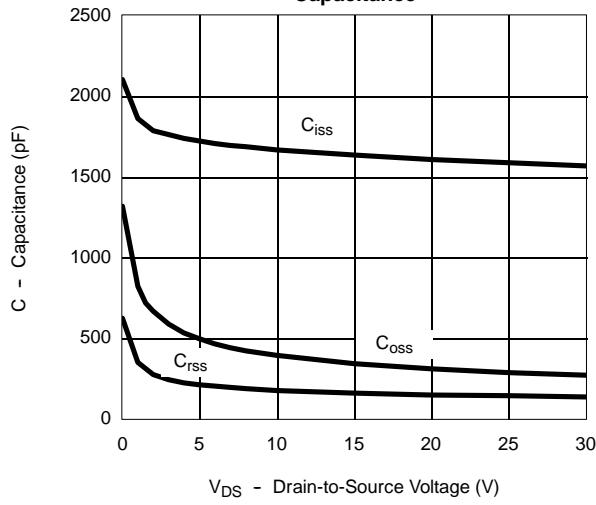
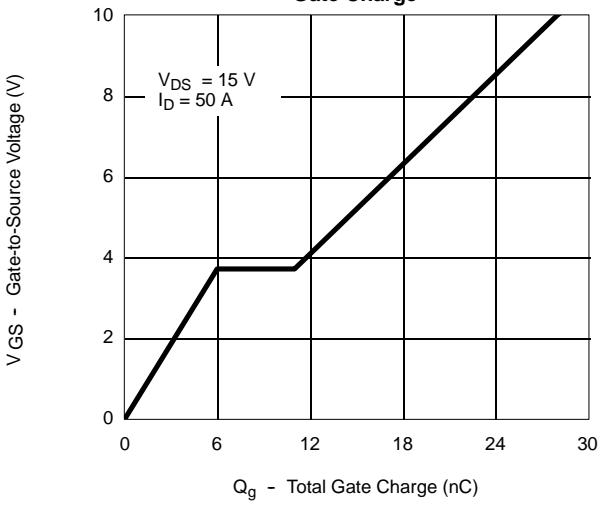
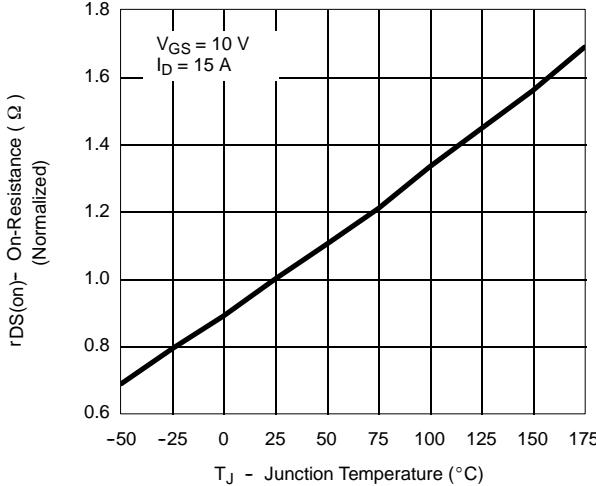
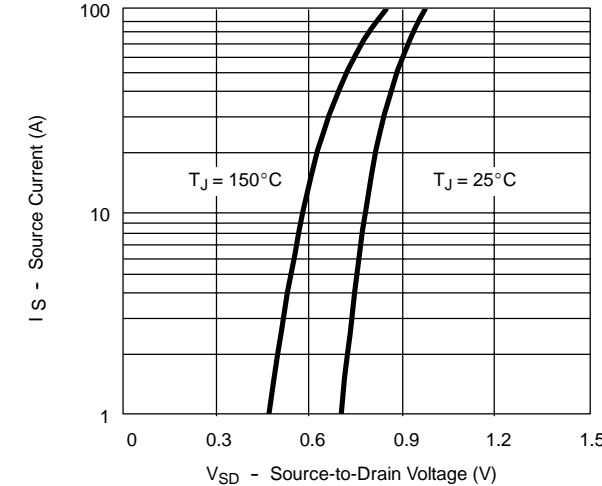
**SPECIFICATIONS ( $T_J = 25^\circ\text{C}$  UNLESS OTHERWISE NOTED)**

Parameter	Symbol	Test Condition	Min	Typ <sup>a</sup>	Max	Unit
<b>Static</b>						
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	30			V
Gate Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$	1.0		3.0	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$		1		$\mu\text{A}$
		$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 125^\circ\text{C}$		50		
On-State Drain Current <sup>b</sup>	$I_{D(\text{on})}$	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			A
Drain-Source On-State Resistance <sup>b</sup>	$r_{DS(\text{on})}$	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		0.010	0.012	
		$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}, T_J = 125^\circ\text{C}$			0.017	$\Omega$
		$V_{GS} = 4.5 \text{ V}, I_D = 15 \text{ A}$		0.0138	0.0175	
Forward Transconductance <sup>b</sup>	$g_{fs}$	$V_{DS} = 15 \text{ V}, I_D = 20 \text{ A}$	15			S
<b>Dynamic<sup>a</sup></b>						
Input Capacitance	$C_{iss}$	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		1600		
Output Capacitance	$C_{oss}$			285		pF
Reverse Transfer Capacitance	$C_{rss}$			140		
Gate Resistance	$R_g$			1.5		$\Omega$
Total Gate Charge <sup>c</sup>	$Q_g$	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 50 \text{ A}$		28	42	
Gate-Source Charge <sup>c</sup>	$Q_{gs}$			6.0		nC
Gate-Drain Charge <sup>c</sup>	$Q_{gd}$			5.0		
Turn-On Delay Time <sup>c</sup>	$t_{d(on)}$	$V_{DD} = 15 \text{ V}, R_L = 0.3 \Omega$ $I_D \approx 50 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 2.5 \Omega$		9	15	
Rise Time <sup>c</sup>	$t_r$			15	25	
Turn-Off Delay Time <sup>c</sup>	$t_{d(off)}$			20	30	
Fall Time <sup>c</sup>	$t_f$			12	20	ns
<b>Source-Drain Diode Ratings and Characteristic (<math>T_C = 25^\circ\text{C}</math>)</b>						
Pulsed Current	$I_{SM}$				100	A
Diode Forward Voltage <sup>b</sup>	$V_{SD}$	$I_F = 40 \text{ A}, V_{GS} = 0 \text{ V}$		1.2	1.5	V
Source-Drain Reverse Recovery Time	$t_{rr}$	$I_F = 50 \text{ A}, di/dt = 100 \text{ A}/\mu\text{s}$		25	70	ns

## Notes

- a. Guaranteed by design, not subject to production testing.
- b. Pulse test; pulse width  $\leq 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .
- c. Independent of operating temperature.

**TYPICAL CHARACTERISTICS ( $25^\circ\text{C}$  UNLESS NOTED)**

**TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)**
**Transconductance**

**On-Resistance vs. Drain Current**

**Capacitance**

**Gate Charge**

**On-Resistance vs. Junction Temperature**

**Source-Drain Diode Forward Voltage**


**THERMAL RATINGS**